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- Controlled Baseline

 One Assembly/Test Site, One Fabrication Site
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree[†]
- Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$
- Supports Unregulated Battery Operation Down to 2.7 V
- I_{off} and Power-Up 3-State Support Hot Insertion

[†] Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

description/ordering information

- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22

 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

PW PACKAGE (TOP VIEW)									
LEBA [1	24	V _{CC}						
OEBA [2	23	CEBA						
A1]	3	22	B1						
A2 [4	21	B2						
A3]	5	20	B3						
A4 [6	19	B4						
A5]	7	18	B5						
A6 [8	17	B6						
A7]	9	16	B7						
A8 [10	15	B8						
CEAB]	11	14	LEAB						
GND [12	13	OEAB						

This octal transceiver is designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The SN74LVTH543 contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate latch-enable (LEAB or LEBA) and output-enable (OEAB or OEBA) inputs are provided for each register, to permit independent control in either direction of data flow.

The A-to-B enable (CEAB) input must be low to enter data from A or to output data from B. If CEAB is low and LEAB is low, the A-to-B latches are transparent; a subsequent low-to-high transition of LEAB puts the A latches in the storage mode. With CEAB and OEAB both low, the 3-state B outputs are active and reflect the data present at the output of the A latches. Data flow from B to A is similar, but requires using the CEBA, LEBA, and OEBA inputs.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

ORDERING INFORMATION											
TA	PACKA	AGE [‡]	ORDERABLE PART NUMBER	TOP-SIDE MARKING							
–40°C to 85°C	TSSOP – PW	Tape and reel	SN74LVTH543IPWREP	LH543EP							

ORDERING INFORMATION

‡ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

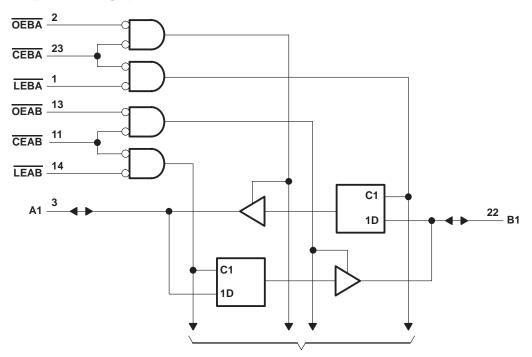
	INPUTS									
CEAB	LEAB	OEAB	Α	В						
Н	Х	Х	Х	Z						
Х	Х	Н	Х	Z						
L	Н	L	Х	в ₀ ‡						
L	L	L	L	L						
L	L	L	Н	Н						

FUNCTION TABLE[†]

[†] A-to-B data flow is shown; B-to-A flow control is the same, except that it uses CEBA, LEBA, and OEBA.

‡Output level before the indicated steady-state input conditions were established

logic diagram (positive logic)



To Seven Other Channels



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	\ldots –0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	\dots –0.5 V to V _{CC} + 0.5 V
Current into any output in the low state, IO	128 mA
Current into any output in the high state, I _O (see Note 2)	64 mA
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ_{JA} (see Note 3)	
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$. 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
VCC	Supply voltage		2.7	3.6	V
VIH	High-level input voltage		2		V
VIL	Low-level input voltage			0.8	V
VI	Input voltage			5.5	V
ЮН	High-level output current			-32	mA
IOL	Low-level output current			64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate Outp	outs enabled		10	ns/V
∆t/∆V _{CC}	Power-up ramp rate		200		μs/V
Т _А	Operating free-air temperature		-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIO	INS	MIN	TYP†	MAX	UNIT		
VIK		V _{CC} = 2.7 V,	lj = -18 mA			-1.2	V		
		V _{CC} = 2.7 V to 3.6 V,	I _{OH} = –100 μA	V _{CC} -0	.2				
∨он		V _{CC} = 2.7 V,	I _{OH} = –8 mA	2.4			V		
		V _{CC} = 3 V,	I _{OH} = -32 mA	2					
		N 07V	I _{OL} = 100 μA			0.2			
		$V_{CC} = 2.7 V$	I _{OL} = 24 mA			0.5			
VOL			I _{OL} = 16 mA			0.4	V		
		$V_{CC} = 3 V$	I _{OL} = 32 mA			0.5			
			I _{OL} = 64 mA			0.55			
		V _{CC} = 3.6 V,	$V_{I} = V_{CC} \text{ or } GND$			±1			
	Control inputs	V _{CC} = 0 or 3.6 V,	VI = 5.5 V			10			
II A or B ports [‡]			VI = 5.5 V			20	μA		
	A or B ports‡	V _{CC} = 3.6 V	$V_{I} = V_{CC}$			1			
		$V_{I} = 0$		-5					
loff		$V_{CC} = 0,$	V_{I} or $V_{O} = 0$ to 4.5 V			±100	μA		
			VI = 0.8 V	75					
ll(hold)	A or B ports	V _{CC} = 3 V	V _I = 2 V	-75			μA		
· · /		$V_{CC} = 3.6 V$ §	$V_{CC} = 3.6 \ V_{I} = 0 \ \text{to} \ 3.6 \ V$			±500			
IOZPU		$V_{CC} = 0$ to 1.5 V, $V_O = 0.5$ to 3 V, $\overline{OE} = don^3$	't care			±100	μΑ		
IOZPD		V_{CC} = 1.5 V to 0, V_{O} = 0.5 to 3 V, \overline{OE} = don	't care			±100	μΑ		
			Outputs high			0.19			
ICC		$V_{CC} = 3.6 \text{ V}, I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$	Outputs low	5			mA		
			Outputs disabled	0.19					
∆Icc¶		V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V	V, Other inputs at V _{CC} or GND			0.2	mA		
Ci		V _I = 3 V or 0			4		pF		
Cio		V _O = 3 V or 0			9		pF		

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. [‡] Unused terminals are at V_{CC} or GND.

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another. ¶ This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.



SN74LVTH543-EP **3.3-V ABT OCTAL REGISTERED TRANSCEIVER** WITH 3-STATE OUTPUTS SCBS772 - NOVEMBER 2003

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

				۲ <mark>۰۵</mark> × V _{CC} =		V _{CC} =	2.7 V	UNIT
				MIN	MAX	MIN	MAX	
tw	Pulse duration,	LEAB or LEBA low		3.3		3.3		ns
		A or B before LEAB or LEBA↑ A or B before CEAB or CEBA↑	Data high	0.4		0.4		
	Setup time		Data low	1		1.5		
t _{su}			Data high	0.2		0.2		ns
			Data low	0.7		1.2		
		A or B after	Data high	1.5		0.6		
.	Hold time	LEAB or LEBA↑	Data low	1.3		1.5		-
th		A or B after	Data high	1.6		0.5		ns
		CEAB or CEBA↑	Data low	1.4		1.6		

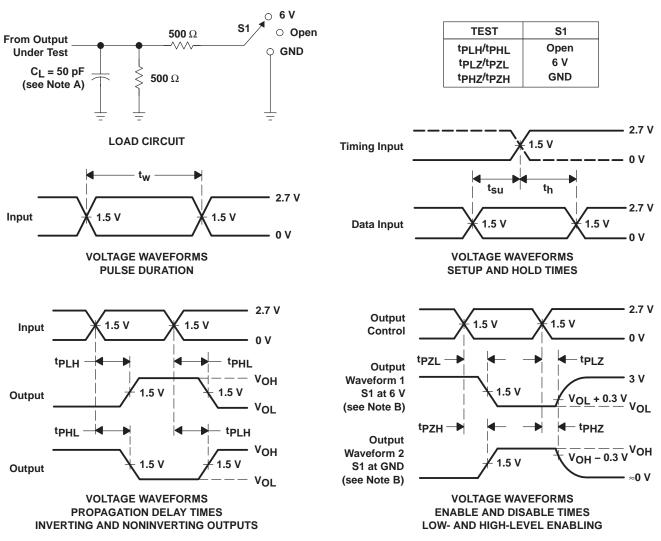
switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO		CC = 3.3 ± 0.3 V	V	VCC =	UNIT	
	(INPUT)	(OUTPUT)	MIN	TYP†	MAX	MIN	MAX	
^t PLH	A at D	DanA	1.3	2.5	3.7		4.3	
^t PHL	A OF B	A or B B or A		2.5	3.7		4.3	ns
^t PLH	LE L	A an D	1.3	2.9	4.7		5.9	
^t PHL	LE	A or B	1.3	2.9	4.7		5.9	ns
^t PZH	OE	A an D	1.1	2.9	4.9		6.2	
^t PZL	OE	A or B	1.1	3.2	4.9		6.2	ns
^t PHZ	OE	A an D	2	3.4	5.3		5.9	
^t PLZ	OE	A or B	2	3.7	5.3		5.9	ns
^t PZH	CE	A or D	1.3	3.2	5.3		6.8	2
^t PZL	CE	CE A or B		3.5	5.3		6.8	ns
^t PHZ	CE	A or B	2.3	3.8	5.4		5.9	ns
^t PLZ	GE	AUD	2.3	3.9	5.4		5.6	115

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CI includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVTH543IPWREP	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH543EP	Samples
V62/04677-01XE	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LH543EP	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF SN74LVTH543-EP :

• Catalog: SN74LVTH543

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

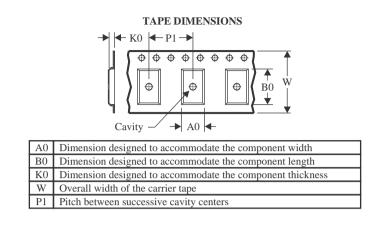


Texas

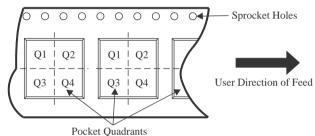
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



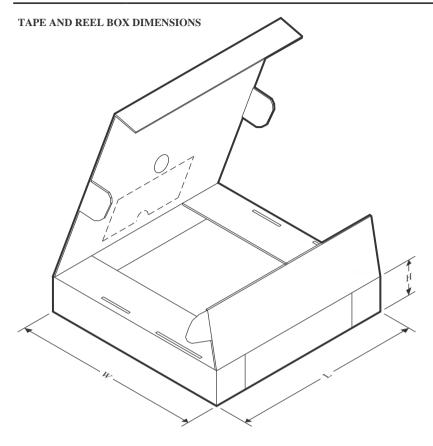
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH543IPWREP	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All	dimensions	are	nominal	
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH543IPWREP	TSSOP	PW	24	2000	356.0	356.0	35.0

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